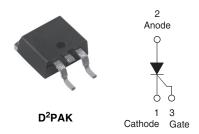


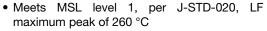
Vishay Semiconductors

Surface Mountable Phase Control SCR, 10 A

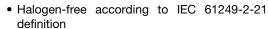


PRODUCT SUMMARY					
V _T at 6.5 A	< 1.15 V				
I _{TSM}	140 A				
V _{RRM}	800 V				

FEATURES







• Designed and qualified for industrial level





ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- Input rectification (soft start)
- Vishay input diodes, switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-10TTS08SPbF High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS	UNITS							
NEMA FR-4 or G-10 glass fabric-based epoxy with 4 oz. (140 μm) copper	2.5	3.5						
Aluminum IMS, R _{thCA} = 15 °C/W	6.3	9.5	А					
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	14.0	18.5						

Note

• $T_A = 55 \,^{\circ}\text{C}$, $T_J = 125 \,^{\circ}\text{C}$, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS								
PARAMETER	TEST CONDITIONS	VALUES	UNITS					
I _{T(AV)}	Sinusoidal waveform	6.5	۸					
I _{RMS}		10	А					
V _{RRM} /V _{DRM}		800	V					
I _{TSM}		140	A					
V _T	6.5 A, T _J = 25 °C	1.15	V					
dV/dt		150	V/µs					
dl/dt		100	A/µs					
T _J	Range	- 40 to 125	°C					

VOLTAGE RATINGS										
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA							
VS-10TTS08SPbF	800	800	1.0							

Document Number: 94562 Revision: 08-Jun-10

Vishay Semiconductors

Surface Mountable Phase Control SCR, 10 A



Document Number: 94562

Revision: 08-Jun-10

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COI	VALUES	UNITS				
Maximum average on-state current	I _{T(AV)}	T 110 °C 100° conduc	tion half ains wave	6.5	•			
Maximum RMS on-state current	I _{T(RMS)}	T _C = 112 °C, 180° conduc	tion hall sine wave	10				
Maximum peak, one-cycle,		10 ms sine pulse, rated V _F	RRM applied, T _J = 125 °C	120	Α			
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no volta	ge reapplied, T _J = 125 °C	140				
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _F	_{RRM} applied, T _J = 125 °C	72	A ² s			
Maximum i-t for fusing	1-1	10 ms sine pulse, no volta	ge reapplied, T _J = 125 °C	100				
Maximum $I^2\sqrt{t}$ for fusing	I ² √t	t = 0.1 ms to 10 ms, no vo	1000	A²√s				
Maximum on-state voltage drop	V _{TM}	6.5 A, T _J = 25 °C	1.15	V				
On-state slope resistance	r _t	T 405 %O		17.3	mΩ			
Threshold voltage	V _{T(TO)}	T _J = 125 °C		0.85	V			
Maximum royares and direct leakage current	1 /1	T _J = 25 °C	V - Batad V A	0.05				
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	V _R = Rated V _{RRM} /V _{DRM}	1.0	^			
Typical holding current	I _H	Anode supply = 6 V, resist	30	mA				
Maximum latching current	ΙL	Anode supply = 6 V, resistive load		50				
Maximum rate of rise of off-state voltage	dV/dt	T _J = 25 °C		150	V/µs			
Maximum rate of rise of turned-on current	dl/dt			100	A/µs			

TRIGGERING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak gate power	P _{GM}		8.0	W			
Maximum average gate power	P _{G(AV)}		2.0	VV			
Maximum peak positive gate current	+I _{GM}		1.5	Α			
Maximum peak negative gate voltage	-V _{GM}		10	٧			
	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	20	mA			
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	15				
		Anode supply = 6 V, resistive load, T _J = 125 °C	10				
		Anode supply = 6 V, resistive load, T _J = - 65 °C	1.2				
Maximum required DC gate voltage to trigger	V _{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	1	V			
voltage to trigger		Anode supply = 6 V, resistive load, T _J = 125 °C	0.7	V			
Maximum DC gate voltage not to trigger V _G		T = 105 °C V = Peted value	0.2				
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = Rated value	0.1	mA			

SWITCHING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Typical turn-on time	t _{gt}	T _J = 25 °C	0.8				
Typical reverse recovery time	t _{rr}	T _J = 125 °C	3	μs			
Typical turn-off time	t _q	1J = 125 G	100				

Surface Mountable Phase Control SCR, 10 A

Vishay Semiconductors

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 125	°C			
Soldering temperature	T _S	For 10 s (1.6 mm from case)	240				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.5	°C/W			
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		40	C/VV			
Approximate weight			2	g			
Approximate weight			0.07	oz.			
Marking device		Case style D ² PAK (SMD-220)	10TTS	08S			

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

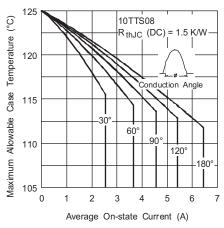


Fig. 1 - Current Rating Characteristics

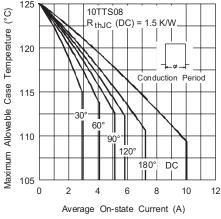


Fig. 2 - Current Rating Characteristics

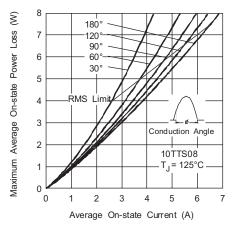


Fig. 3 - On-State Power Loss Characteristics

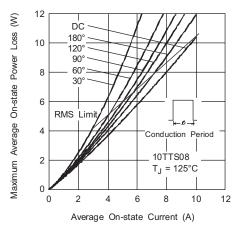


Fig. 4 - On-State Power Loss Characteristics

Vishay Semiconductors

Surface Mountable Phase Control SCR, 10 A



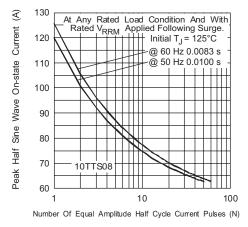


Fig. 5 - Maximum Non-Repetitive Surge Current

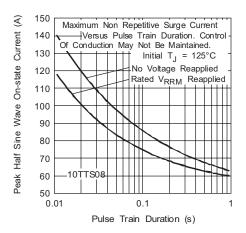


Fig. 6 - Maximum Non-Repetitive Surge Current

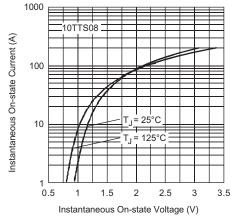


Fig. 7 - On-State Voltage Drop Characteristics

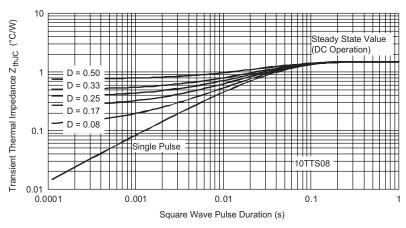


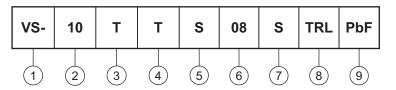
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



Surface Mountable Phase Control SCR, 10 A Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- 1 HPP product suffix
- 2 Current rating, RMS value
- Gircuit configuration:

 T = Single thyristor
- 4 Package:
 - T = TO-220AC
- 5 Type of silicon:
 - S = Converter grade
- 6 Voltage code x 100 = V_{RRM}
- 7 S = TO-220 D^2 PAK (SMD-220) version
- 8 Tape and reel option:
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 9 PbF = Lead (Pb)-free

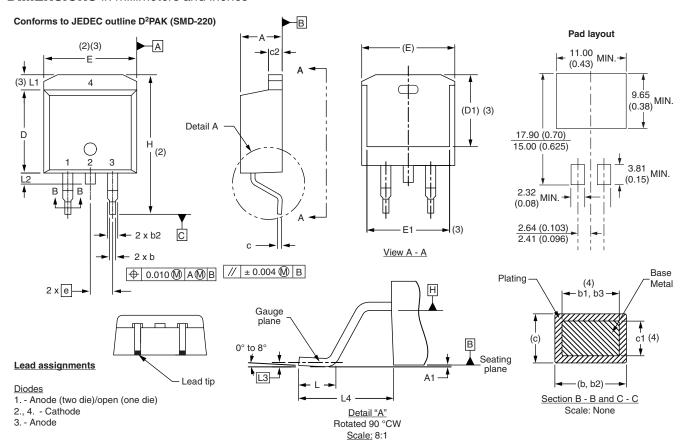
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95046				
Part marking information	www.vishay.com/doc?95054				
Packaging information	www.vishay.com/doc?95032				



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208

Notes

- $^{(1)}$ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB

NOTES

3

2, 3

3

3





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 11-Mar-11